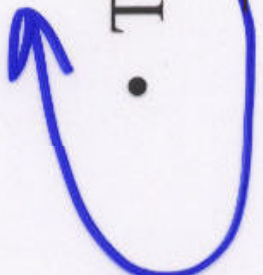


Lecture 7

- Last time:
 - Underdamped 2nd order transfer functions
 - Today :
 - Bode plots for general transfer functions
 - Start: semiconductor properties of Si
- 

H&S Chapter 2

Electronic Properties of Silicon

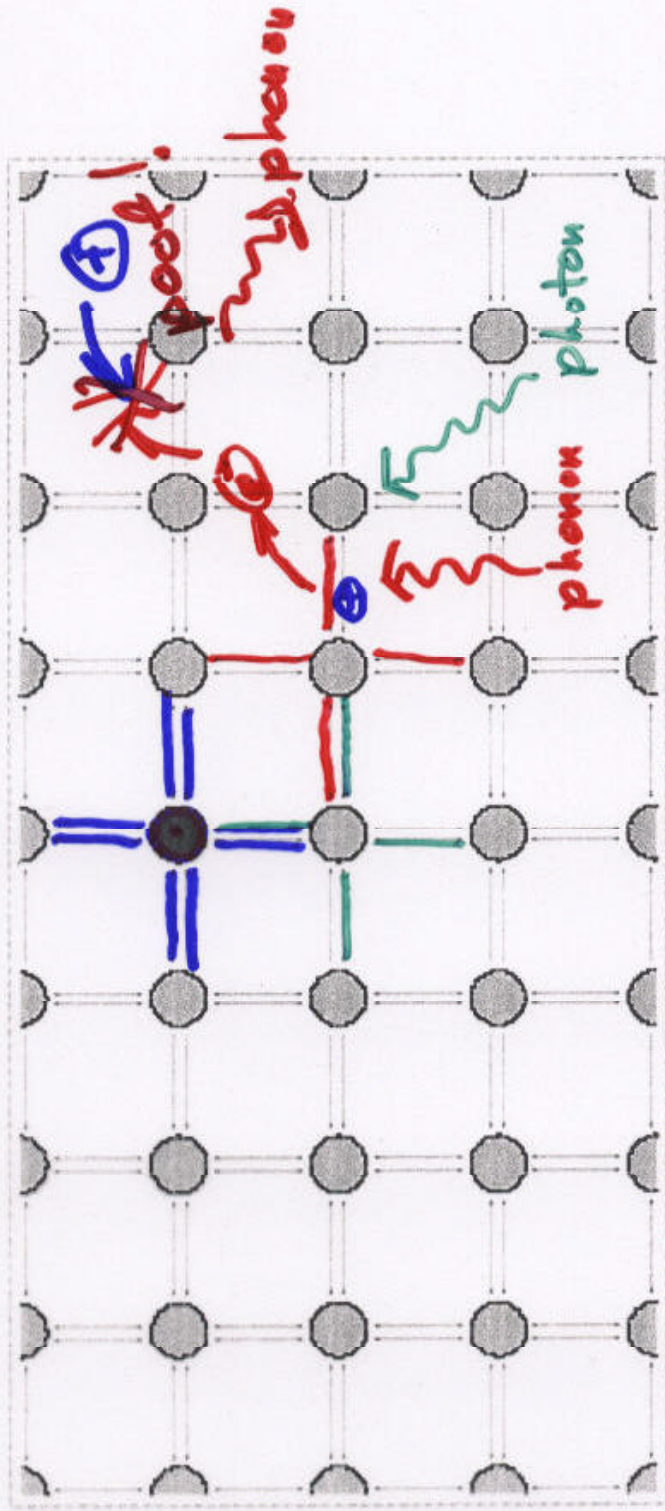
- Silicon is in Group IV
 - Electronic structure: $1s^2 2s^2 2p^6 3(sp)^4$ C, Ge
 - Diamond lattice, with 0.235 nm bond length
- Very poor conductor at room temperature:

why?

nm 10^{-9} mÅ 10^{-10} mμm 10^{-6} m

Bond Model for Silicon

0°K $\rho \rightarrow \infty$



At R.T. $\sim 300^{\circ}\text{K}$ very few free carriers
 $0^{\circ} \rightarrow 50 \rightarrow 100^{\circ}\text{C}$

Thermal Equilibrium (Pure Si)

- Balance between generation and recombination determines $n_o = p_o$ $n = \# \text{elec}/\text{cm}^3$ $p = \# \text{holes}/\text{cm}^3$
- Strong function of temperature: $T = 300 \text{ K}$

$G(T)$ at a given temp $G = \text{const}$

$$R = K(n \cdot p)$$

at T.E. $G = R = \text{const}$

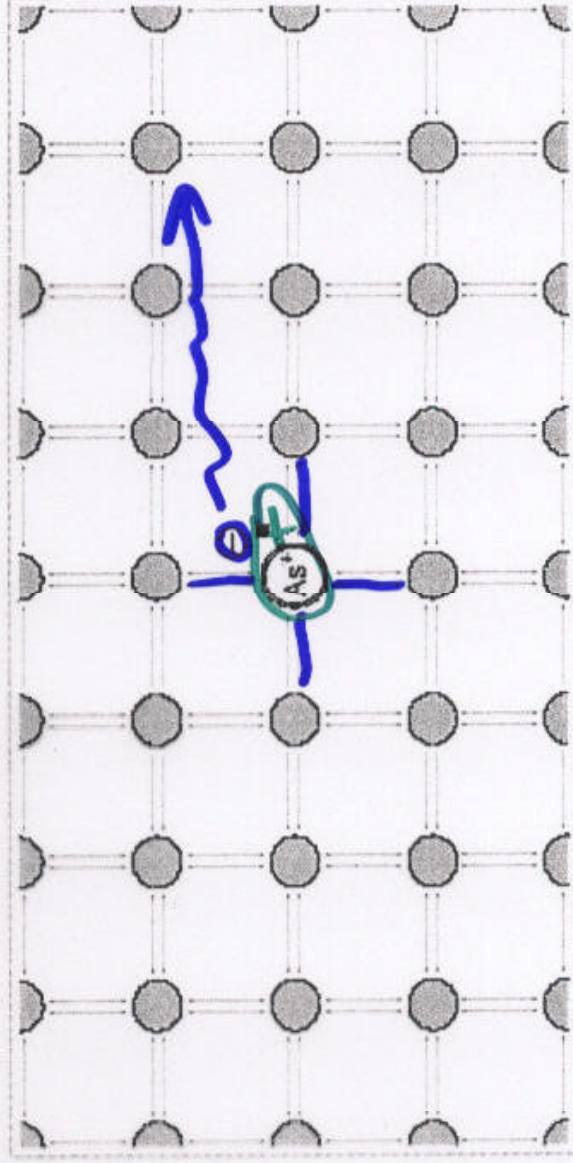
$$\Rightarrow n_o \cdot p_o = \text{const}$$

Doping with Group V Elements

phosphorus
Arsonic

5 valence electrons

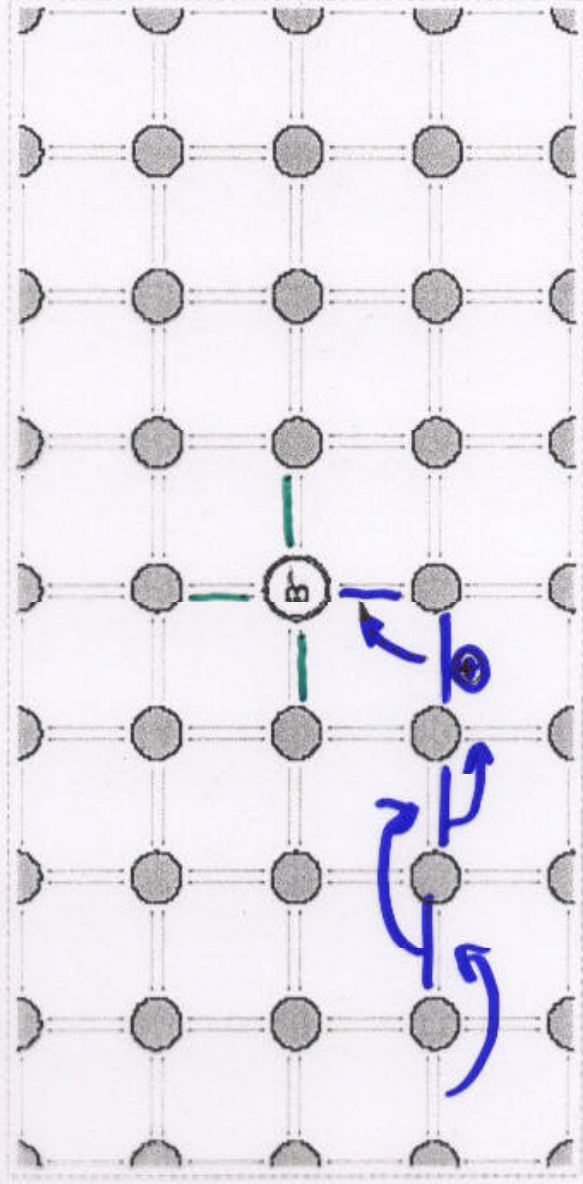
- P, As: extra bonding electron ... lost to crystal at room temperature



Doping with Group III Elements

3 valence electrons

- Boron: 3 bonding electrons \rightarrow one bond is unsaturated



Physics 137

ee 131

Mass Action Law

- Balance between generation and recombination:

$$p_0 \cdot n_0 = \text{const}$$

$$n_i = p_i \approx 10^{10} \text{ cm}^{-3}$$

$$p_0 \cdot n_0 = n_i^2 = 10^{20} \text{ in intrinsic}$$

- N-type case:

$$n_0 \approx N_d \quad p_0 = \frac{n_i^2}{N_d}$$

$$N_d \neq \text{donors} / \text{cm}^3$$

$$N_d \ 10^{14} \rightarrow 10^{19} \text{ cm}^{-3}$$

- P-type case:

$$p_0 = N_a \quad n_0 = \frac{n_i^2}{N_a}$$

$$N_d = 10^{16} \text{ cm}^{-3}$$

$$n_0 = 10^{16}$$

$$p_0 = \frac{10^{20}}{10^{16}} = 10^4 \text{ cm}^{-3}$$

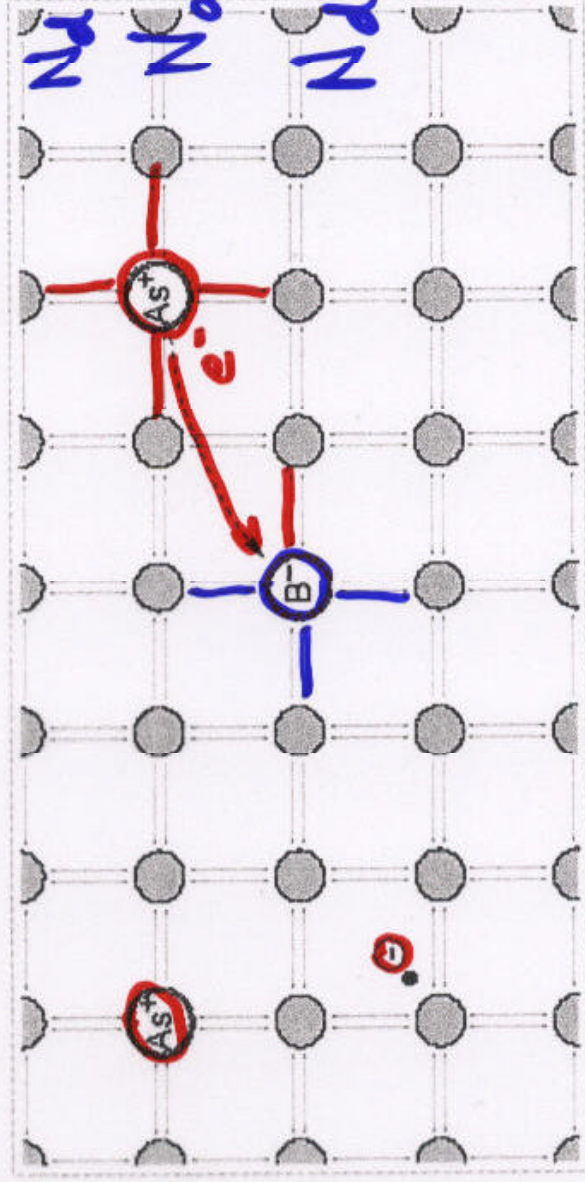
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 $N_a = \# \text{ acceptors per cm}^3$
 $N_a = \# \text{ acceptors}$
n-type

Compensation

- Dope with *both* donors and acceptors



$$N_d \approx 10^{16} \text{ cm}^{-3}$$

$$N_a \approx 10^{16} \text{ cm}^{-3}$$

$$N_d = 1.001 \times 10^{16}$$

$$N_a = .999 \times 10^{16}$$

$$N_d - N_a = 2 \times 10^{13} \text{ cm}^{-3}$$

$$\gg n_i = 10^{10}$$

Hard messy formula

$$N_d - N_a \gg n_i$$

$$N_a - N_d \gg n_i$$

- More donors than acceptors: $N_d > N_a$

$$n_o = N_d - N_a$$

$$p_o = \frac{n_i^2}{N_d - N_a}$$

Mass Action

- Hole concentration:

More acceptors than donors $N_a > N_d$

$$p_o = N_a - N_d$$

$$n_o = \frac{n_i^2}{N_a - N_d}$$

$$n_o \rightarrow p \gg R$$